

Features

- High Current and Low Voltage
- Halogen Free. "Green" Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

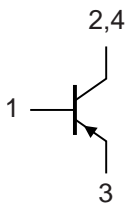
Maximum Ratings @ 25°C Unless Otherwise Specified

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 125°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	-32	V
Collector-Emitter Voltage	V_{CEO}	-20	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-1	A
Power Dissipation	P_D	1	W

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

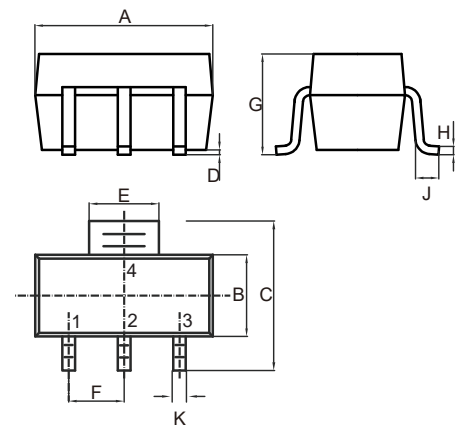
Internal Structure



1.BASE
2,4.COLLECTOR
3.EMITTER

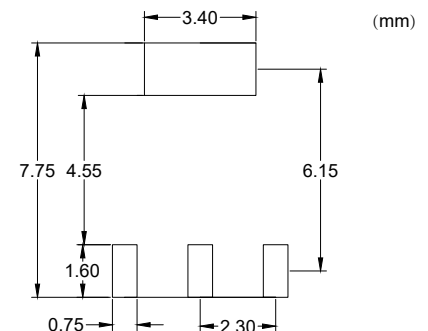
**PNP
Plastic-Encapsulate
Transistors**

SOT-223



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.248	0.264	6.30	6.70	
B	0.130	0.146	3.30	3.70	
C	0.264	0.287	6.70	7.30	
D	0.001	0.004	0.02	0.10	
E	0.114	0.122	2.90	3.10	
F	0.091		2.30		TYP.
G	---	0.071	---	1.80	
H	0.009	0.014	0.23	0.35	
J	0.030	---	0.75	---	
K	0.026	0.033	0.66	0.84	

Suggested Solder Pad Layout



Electrical Characteristics @ $T_A=25^\circ\text{C}$ Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-32			V	$I_C=-100\mu\text{A}, I_E=0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-20			V	$I_C=-1\text{mA}, I_B=0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5			V	$I_E=-100\mu\text{A}, I_C=0$
Collector-Base Cutoff Current	I_{CBO}			-100	nA	$V_{CB}=-25\text{V}, I_E=0$
Emitter-Base Cutoff Current	I_{EBO}			-100	nA	$V_{EB}=-5\text{V}, I_C=0$
DC Current Gain	$h_{FE(1)}$	85		375		$V_{CE}=-1\text{V}, I_C=-0.5\text{A}$
	$h_{FE(2)}$	60				$V_{CE}=-1\text{V}, I_C=-1\text{A}$
	$h_{FE(3)}$	50				$V_{CE}=-10\text{V}, I_C=-5\text{mA}$
	$h_{FE(4)}$	140				$V_{CE}=-1.8\text{V}, I_C=-10\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-0.5	V	$I_C=-1\text{A}, I_B=-100\text{mA}$
Base-Emitter Voltage	V_{BE}			-0.68	V	$V_{CE}=-10\text{V}, I_C=-5\text{mA}$
				-1.0	V	$V_{CE}=-1\text{V}, I_C=-1\text{A}$
Transition Frequency	f_T	40			MHz	$V_{CE}=-5\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$
Collector Output Capacitance	C_{ob}		48		pF	$V_{CB}=-5\text{V}, I_E=0, f=1\text{MHz}$

Classification of $h_{FE(1)}$

Rank	BCP69-16	BCP69-25
Range	100~250	160~375
Marking	BCP69-16	BCP69-25